# NSN 5961-01-394-4660

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#### Inclosure Material:

Plastic and metal

#### **Overall Length:**

1.235 inches

## Internal Configuration:

Field effect

# Joint Electronic Device Engineering Council/jedec/case Outline Designation:

Tp-254aa

## Mounting Method:

Terminal

## Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

400.0 breakdown voltage, gate-to-source, with all other terminals short-circuited to source

## Test Data Document:

81349-mil-s-19500/592 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

# Terminal Type And Quantity:

3 uninsulated wire lead

## Specification Data:

81349-mil-s-19500 government specification

## **Specification Or Standard:**

Fy selection

Shelf Life:

N/a

## Unit Of Measure:

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## Demilitarization:

No

## Fiig:

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